

Electron pairing in the presence of incipient bands in iron-based superconductorsXiao Chen,¹ S. Maiti,^{1,2} A. Linscheid,¹ and P. J. Hirschfeld¹¹*Department of Physics, University of Florida, Gainesville, Florida 32611, USA*²*National High Magnetic Field Laboratory, Tallahassee, Florida 32310, USA*

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Recent experiments on certain Fe-based superconductors have hinted at a role for paired electrons in “incipient” bands that are close to, but do not cross, the Fermi level. Related theoretical works disagree on whether or not strong-coupling superconductivity is required to explain such effects, and whether a critical interaction strength exists. In this work, we consider various versions of the model problem of pairing of electrons in the presence of an incipient band, within a simple multiband weak-coupling BCS approximation. We categorize the problem into two cases: case (i), where superconductivity arises from the “incipient band pairing” alone, and case (ii), where it is induced on an incipient band by pairing due to Fermi-surface-based interactions. Negative conclusions regarding the importance of incipient bands have been drawn so far largely based on case (i), but we show explicitly that models under case (ii) are qualitatively different, and can explain the nonexponential suppression of T_c , as well as robust large gaps on an incipient band. In the latter situation, large gaps on the incipient band do not require a critical interaction strength. We also model the interplay between phonon and spin fluctuation driven superconductivity and describe situations in which they can enhance each other rather than compete. Finally, we discuss the effect of the dimensionality of the incipient band on our results. We argue that pairing on incipient bands may be significant and important in several Fe-based materials, including LiFeAs, FeSe intercalates, and FeSe monolayers on strontium titanate, and indeed may contribute to high critical temperatures in some cases.

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I. INTRODUCTION

The standard paradigm for s_{\pm} pairing in Fe-based superconductors (FeSC) [1–5] relies on the existence of a holelike Fermi surface (FS) near $\vec{k} = 0$ and an electronlike FS near $\vec{k}' = (\pi, 0)$ in the 1-Fe Brillouin zone, and symmetry-related points. Repulsive interband interactions and approximate nesting then lead, within this simplified picture, to a strong peak in the particle-hole susceptibility at $\vec{q} = \vec{k} - \vec{k}' = (\pi, 0)$, which drives a spin fluctuation pairing interaction that can condense pairs only if the superconducting (SC) order parameter changes sign between the two pockets [6,7]. Beginning in 2010 with the discovery of superconductivity in the alkali-intercalated FeSe materials [8–10], this paradigm was challenged by the subsequent remarkable discovery [11–13] that all hole bands in these materials, with optimal critical temperatures greater than 40 K, were below the Fermi level. Several groups pointed out that repulsive interactions at the Fermi level remained among the electron Fermi-surface pockets, and could lead to d -wave pairing with significant critical temperatures [13,14].

Reference [13] also pointed out that pairing in an s_{\pm} channel with sign-changing gap was still quite competitive, despite the fact that the hole band was ~ 90 meV below the Fermi level, indicating presence of substantial spectral weight of the spin fluctuations. While this “incipient” s_{\pm} possibility was considered [3], along with the d -wave state and a more subtle s -wave state that changed sign between two hybridized electron pockets in the 2-Fe zone, as a possible candidate for pairing in these materials, it did not receive a great deal of attention. This is probably because of the general feeling in the community that incipient bands (we use this term “incipient” here to mean bands away from the Fermi level, but within a “pairing” cutoff energy) do not play an important role in superconductivity. As discussed in Ref. [3], in a simple model of electron-pocket-hole-pocket s_{\pm} pairing, if the hole-pocket maximum moves below the Fermi

level by an energy $|E_g|$, the dimensionless pairing strength (v) in this channel is reduced: $v \rightarrow v^2 \ln \Lambda / |E_g|$, where Λ is the pairing cutoff. This suggests that within weak-coupling theories, one gets a strong suppression of T_c as $|E_g|$ is increased.

The discussion of the role of the incipient band in pairing in FeSCs was revived by several new experiments. The first was the discovery by angle-resolved photoemission (ARPES) that the electronic dispersion in FeSe monolayers on SrTiO₃ (STO), with extremely high critical temperatures of around 70 K (ARPES gap closing) [15], was similar to the alkali-intercalated FeSe systems, namely, the central hole pocket was pushed below the Fermi surface by ~ 80 meV. The second was the observation by Miao *et al.* [16] of a superconducting gap on one of the hole bands of LiFeAs as it fell below the Fermi level with electron doping by Co. Here, it was found that the gap was suppressed only rather weakly in this process, compared to one’s naive expectations according to weak-coupling BCS theory, and survived at least up to band extremum values of $E_g \sim -8$ meV. These authors suggested that, because the variation of the gap on the hole band was gradual through the Lifshitz transition, a standard weak-coupling scenario was unlikely. Finally, a more recent experiment has reported a Fermi surface without hole pockets, very similar to the FeSe monolayers, in the new LiFeOH-intercalated FeSe material [17].

There have been some theoretical efforts addressing these systems and the idea of incipient band pairing. The most systematic work on Fe-based superconductors thus far is from Bang [18], who explored the evolution of T_c across a Lifshitz transition in a model for $\text{Ba}_{1-x}\text{K}_x(\text{FeAs})_2$. He pointed out that T_c may remain substantial in the presence of an attractive intraband interaction. Considering only interband interactions, Bang also concluded that the gap induced in the incipient band will be significant and should show up as a

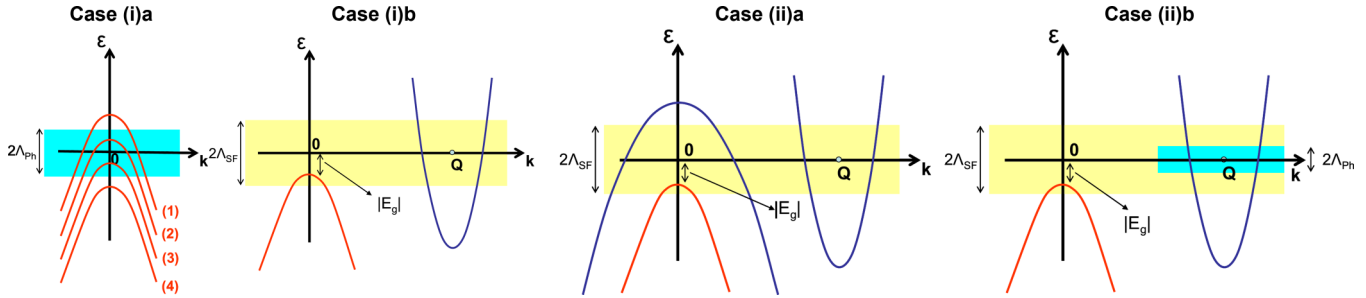


FIG. 1. (Color online) Case (i)a: The four instances of the hole band correspond to (1) regular band, (2) shallow band, (3) incipient band, and (4) vegetable band. This is a representation of a conventional case with phonon driven interactions with cutoff Λ_{ph} (blue region). Case (i)b: Representative of the incipient case for spin fluctuation driven (cutoff Λ_{sf} , yellow region) SC. Case (ii)a: Representative of the incipient case for the situation where SC is driven by spin fluctuations in the regular (blue) bands. SC in the incipient band is induced by the same interaction. Case (ii)b: Representative of the incipient case for the situation where SC is driven by phonons in the regular (blue) band. SC is induced in the incipient band through spin fluctuations.

shadow gap in the ARPES spectrum. Leong and Phillips [19] recently also considered a model specific to LiFeAs within weak-coupling Eliashberg theory and argued that Coulomb interactions can stabilize a robust isotropic gap in a “shallow” band which barely crosses the FS. Hu *et al.* [20] attempted a more realistic calculation of the effect of an incipient band in the LiFeAs system, and concluded that one needs to consider large couplings in order to explain the experiments, and also a minimum pairing interaction to induce a gap on the incipient band, which is apparently contrary to the message in Bang’s work. Koshelev and Matveev discussed the quasiparticle density of states on both sides of the Lifshitz transition of a two-band superconductor [21]. Finally, Innocenti *et al.* [22] considered the effect of Lifshitz transition on the critical temperature with an attractive two-band BCS model.

In this work, we extend Bang’s idea, within a simple multiband BCS approximation, to perform a systematic study of pairing in the incipient band in FeSCs. We clarify that there are two classes of problems that arise: (i) when pairing is driven by interactions only with the incipient band; and (ii) when pairing is induced in the incipient band due to an already stabilized SC ground state due to other bands that cross the Fermi level. We argue that, unlike the result in Hu *et al.*, there is no minimum interaction strength except for a special instance of case (i). We show that the usual expectation of strong suppression of gaps and T_c apply only to case (i). The models for case (ii) suggest that (a) the problem is well defined and can be treated in weak coupling; (b) there is no minimum interaction strength needed to induce SC; (c) the induced gap on the incipient band is comparable to and can be larger than other gaps in the system; (d) spin fluctuations (interband interactions) are crucial to induce significant pairing in the incipient band; (e) spin fluctuations can bootstrap an existing phonon based interaction and yield a larger T_c and a sizable SC gap; (f) the dimensionality of the incipient band can play a role in determining the magnitude of the effect on SC.

We arrange the paper in the following way: In Sec. II, we discuss the formulation of cases (i) and (ii) and discuss the literature in some detail; in Sec. III, we discuss case (i) where standard results are recovered. In Sec. IV, our main section, we discuss all aspects of case (ii) and compare with the results mentioned above. In Sec. V, we present our ideas in the

context of the experimental situation via a vis particular FeSC materials, and summarize in Sec. VI. In the Appendix, we summarize the effect of three dimensionality of the density of states (DOS) in the incipient hole band on the results obtained in this work.

II. MODELS FOR SC IN THE INCIPIENT BAND

The two cases mentioned in the Introduction need to be distinguished, as they give fundamentally different results. We have sketched the various possibilities in Fig. 1. Case (i)a, which considers pairing in the incipient band when the driving pairing interaction (phonon mediated, i.e., attractive) involves states in the incipient band itself, is the case usually imagined when the irrelevance of incipient band pairing is claimed. Case (i)b considers spin fluctuation as the driving pairing interaction that connects a regular band and an incipient band. This was discussed in Ref. [3] and numerically explored by Bang [18], with the result that T_c is drastically suppressed as the incipient band extremum $|E_g|$ is increased, unless an attractive intraband interaction is present. Our study of case (ii) is also comprised of two categories, which we use to explore spin fluctuation driven SC and phonon driven SC. In case (ii)a, a (repulsive) spin fluctuation mediated (pairing cutoff Λ_{sf}) SC is stabilized in the already existing bands, and the same spin fluctuations induce SC in the incipient band. In case (ii)b, an (attractive) phonon mediated (pairing cutoff Λ_{ph}) interaction results in SC in the electron pockets and the spin fluctuations induce SC on the incipient hole band. We assume here that interband phonon coupling is weak. This will serve as our paradigm for spin fluctuations bootstrapping the electron-phonon mediated SC.

We take this opportunity to comment on some other works addressing incipient band pairing. Miao *et al.* presented a curve labeled “BCS weak coupling” which indicates a gap on the incipient band falling rapidly compared with experiment as the band sinks below the Fermi level, without giving details of the calculation. They imply that this disagreement rules out BCS weak-coupling-type physics. Furthermore, they argue that the large size of the gap on the incipient band rules out “proximity-coupled” superconductivity, i.e., the possibility that the superconductivity caused by pairing of states at the

Fermi level in other bands could induce a large gap in the incipient band.

In the work by Hu *et al.* [20], the experiment in Ref. [16] motivated them to study a more realistic three-orbital model for LiFeAs with a next-nearest-neighbor intersite BCS-type pairing ansatz. These authors claimed that the results of the experiment could be understood on the basis of requiring a strong pairing strength coupling the incipient band to the Fermi-surface pocket and having a minimum threshold for the pairing strength, thereby suggesting that strong-coupling physics is required. We believe that this conclusion is incorrect and, in fact, will show that the strict requirement for a minimum pairing strength only arises in case (i)a, and hence is not applicable to FeSCs. We discuss this point further in the following.

Another realistic model was studied in Ref. [19] where a five-band model was considered with spin fluctuation interactions scattering electrons near the Fermi surface, and Coulomb interactions renormalized to a low-energy cutoff scattering electrons from a shallow band to one of the other hole bands. While these authors reported an enhanced T_c and the largest gap on the shallow pocket, some caveats remain: (1) For the tiny shallow pocket, one might expect the Coulomb repulsion to be strong within the band, yet this was dropped, retaining only a repulsive interband Coulomb interaction with the other hole band; (2), a constant DOS was assumed in the derivation of the Eliashberg equations used, despite the low-energy scale of the shallow band; (3) strictly speaking, incipient band pairing was still not considered.

The work by Bang [18] correctly captured the idea of incipient band pairing, and also pointed out that the induced gaps may be significant in the incipient case. However, he specialized to parameters appropriate for $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$, where T_c had been observed to vary only weakly through a Lifshitz transition [23].

We keep the modeling simple and extend Bang's idea systematically to all the cases mentioned above, allowing us to discuss analytical results in important cases. We study the gradual evolution of the gaps and T_c for every case and show that models representing case (ii) have the potential to explain the recent experiments.

We emphasize that to get a simple qualitative picture we will restrict ourselves to the static approximation to the pairing interaction. In this way of modeling, the complicated frequency structure of the interactions is not considered, but at least the energy range of the dynamical interactions is reflected in the choice of the cutoffs for various pairing interactions. For instance, in the electron-phonon problem, the renormalizations due to phonons lead to attraction between electrons only if they exchange energies below Λ_{ph} (whose scale is set by the Debye frequency of the lattice). In the static approximation for the attractive part of the pairing interaction, this energy dependence is mapped to a cutoff on the fermionic energy states (measured relative to the Fermi level). A similar mapping is carried out for systems exhibiting strong spin correlations. Here, however, the pairing channel is strongly influenced by fluctuations in the spin sector. However, renormalization group studies [24,25] have shown that one can construct an effective BCS-type pairing channel below Λ_{sf} whose scale is set by the energies over which spin fluctuation exchanges are effective,

which is usually a fraction of the Fermi energy. While a general hierarchy of the cutoffs can be established ($\Lambda_{\text{sf}} > \Lambda_{\text{ph}}$), the determination of T_c also requires the knowledge of the coupling constant determined by microscopic details of the system. This is modeled by controlling the magnitude of our static interaction.

III. SC IN INCIPIENT BAND: CASE (i)

For completeness, we revisit the conventional case (i) in some detail and show, within weak coupling, how one can qualitatively reproduce the previously known results. Since this part is intended to be a demonstration of principle, we strive to keep the presentation of case (i)a (see Fig. 1) simple. The multiband case (i)b follows from a treatment similar to that presented in Ref. [18], so we do not dwell on details.

A. Case (i)a

Within the weak-coupling BCS treatment of the problem, our simple one-band example (i)a involves solving the following gap equation at temperature T (with $\hbar = k_B = 1$ and unit volume):

$$\Delta_{\vec{k}} = - \int \frac{d^2k}{(2\pi)^2} V_{\vec{k},\vec{k}'} \frac{\Delta_{\vec{k}'}}{2E_{\vec{k}'}} \tanh \frac{E_{\vec{k}'}}{2T}, \quad (1)$$

where $E_{\vec{k}} = \sqrt{\varepsilon_{\vec{k}}^2 + \Delta_{\vec{k}}^2}$. The hole band dispersion is

$$\varepsilon_{\vec{k}} = -\frac{k^2}{2m} + E_g, \quad (2)$$

where m is the band mass and E_g is the shift of the hole band. We work with energies relative to the chemical potential μ and hence set $\mu = 0$. $E_g > \Lambda$ is the regular BCS case (instance 1), $\Lambda > E_g > 0$ corresponds to the shallow band case (instance 2), $0 > E_g > -\Lambda$ corresponds to the incipient case (instance 3), and $-\Lambda > E_g$ is the vegetable case (instance 4) where the band does not participate in SC. Choosing the (attractive intraband) pairing interaction $V_{\vec{k},\vec{k}'} = V_{\text{ph}} < 0$ for $|\varepsilon_{\vec{k}}|, |\varepsilon_{\vec{k}'}| < \Lambda$, the order parameter $\Delta_{\vec{k}}$ becomes a constant Δ . After we solve these equations, we get T_c as a function of E_g . As long as $E_g > \Lambda$, we remain in the conventional BCS regime (instance 1 in Fig. 1). Interesting effects arise when the band becomes shallow (instance 2) and incipient (instance 3). This marks the first step of departure from a conventional BCS approach because the band edge now falls within the pairing energy scale. Already at this stage we note that all the corrections to the BCS theory of $O(\Lambda/E_F)$ and phase fluctuations become relevant.

Accounting for the cutoff of available hole states at E_g implies that the gap equation loses particle-hole symmetry and takes the form

$$1 = -\frac{mV_{\text{ph}}}{2\pi} \left[\int_{-\Lambda}^0 \frac{d\varepsilon}{2E} \tanh \frac{E}{2T} + \int_0^{E_g} \frac{d\varepsilon}{2E} \tanh \frac{E}{2T} \right] \quad \text{for instance 2,}$$

$$1 = -\frac{mV_{\text{ph}}}{2\pi} \left[\int_{-\Lambda}^{-|E_g|} \frac{d\varepsilon}{2E} \tanh \frac{E}{2T} \right] \quad \text{for instance 3.} \quad (3)$$

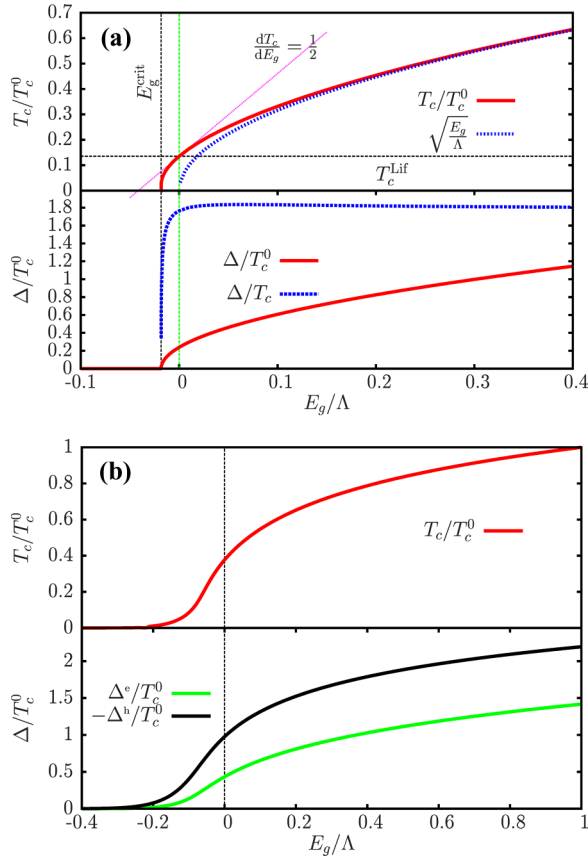


FIG. 2. (Color online) (a) T_c and gap as a function of E_g for case (i)a. All the special lines are explained in the text. (b) The same for case (i)b, also discussed in Ref. [18]. The normalization is with respect to T_c^0 , the critical temperature when $E_g > \Lambda$. The dimensionless interactions were taken to be $v_{\text{ph}} = -0.5$ in (a) and $v_{\text{sf}} = 0.3$ in (b).

To solve for T_c , we note that $E \rightarrow |\varepsilon|$. The solution of T_c with E_g is shown in Fig. 2. One can get analytical expressions for some interesting regimes:

The *shallow band* ($E_g \lesssim \Lambda$) region gives ($T_c \ll E_g$)

$$\frac{T_c}{T_c^0} = \sqrt{\frac{E_g}{\Lambda}}, \quad (4)$$

where T_c^0 is the weak-coupling critical temperature for $E_g > \Lambda$ and is given by $T_c^0 = \frac{2e^\gamma}{\pi} \Lambda e^{1/v_{\text{ph}}}$ (γ is Euler's constant) and $v_{\text{ph}} = mV_{\text{ph}}/2\pi$. We refrain from using the term ‘‘density of states’’ for $m/2\pi$ as it is usually reserved for states at the Fermi level.

This has a physical relevance because close to the Lifshitz transition, the mass can be treated as constant within the pairing cutoff for a general dispersion.

Near the *Lifshitz transition* ($E_g \sim 0$) we formally obtain

$$T_c = T_c^{\text{Lif}} + \frac{E_g}{2}, \quad (5)$$

where

$$T_c^{\text{Lif}} = T_c^0 e^{\frac{1}{v_{\text{ph}}}} \quad (6)$$

is the critical temperature at the Lifshitz point which is obtained by setting $E_g = 0$ in Eq. (3). The behavior of T_c obtained from the above equations as a function of E_g can be seen in the top panel of Fig. 2. It is clear that superconductivity in the system is suppressed rapidly as E_g falls below zero, as expected. The gap on the incipient band is related to T_c by the standard BCS ratio ~ 1.76 until almost the incipient point $E_g = 0$, before it drops drastically and vanishes at the critical E_g^{crit} .

E_g^{crit} is the final feature of the incipient solution for a single band where SC disappears before the lower cutoff $-\Lambda$ is reached. This is found by setting $T \rightarrow 0$ in Eq. (3) (instance 3). This immediately yields

$$E_g^{\text{crit}} = -\Lambda e^{\frac{2}{v_{\text{ph}}}}. \quad (7)$$

What this also implies is that, for a given $E_g < 0$, v_{ph} cannot be made arbitrarily small and still obtain $T_c > 0$, unlike the conventional BCS paradigm. This is the only case within weak coupling where a threshold problem is encountered for the pairing interaction.

While for our purposes here it is irrelevant, we mention for completeness that in a continuum single-band model, the approach to the Lifshitz transition was studied long ago by Gor'kov and Melik-Barkhudarov, who pointed out that since the spacing between pairs in the one-band case becomes larger than the Cooper pair radius at some point approaching the Lifshitz transition in case (i)a, one enters the BCS Bose-Einstein condensate crossover regime in the low-density limit. If this occurs, T_c should vanish at the Lifshitz point if the problem is treated properly because the BCS equations describe the instability to an incoherent paired bound state [26,27].

B. Case (i)b

The multiband scenario case (i)b with interband interaction V_{sf} (the dimensionless interaction is $v_{\text{sf}} = \sqrt{N_e m}/(2\pi)V_{\text{sf}}$ where N_e is the Fermi level DOS of the electron band) also exhibits a similar strong suppression of T_c [see Fig. 2(b) and Ref. [18]], but does not have a threshold. To see this, note that the gap equations for the two-band problem are

$$\begin{aligned} \Delta_h &= -V_{\text{sf}} L_e \Delta_e, & \Delta_e &= -V_{\text{sf}} L_h \Delta_h; \\ L_e &= N_e \int_{-\Lambda}^{\Lambda} \frac{d\varepsilon}{2E_e} \tanh \frac{E_e}{2T}, \\ L_h &= \frac{m}{2\pi} \int_{-\Lambda}^{E_g} \frac{d\varepsilon}{2E_h} \tanh \frac{E_h}{2T}, \end{aligned} \quad (8)$$

and the T_c equation then reads

$$1 = V_{\text{sf}}^2 L_e L_h. \quad (9)$$

Here, Λ is the cutoff for the interband interaction. For the deep incipient case, if $|E_g| \gg T_c$, only L_e contains $\ln T_c$ and $L_h \sim \ln \Lambda/|E_g|$. This explains (1) why the effective pairing interaction now varies as $V_{\text{sf}}^2 \ln \Lambda/|E_g|$ as mentioned in the Introduction; and (2) why T_c (although strongly suppressed) exists for arbitrarily small V_{sf} . The evolution of the two gaps with E_g is also plotted in Fig. 2. Note that the pairing state has

s_{\pm} structure due to the repulsive interband interaction. Some of these results appeared earlier in Ref. [28].

IV. SC IN INCIPIENT BAND: CASE (ii)

We now switch to the discussion which presents the main message of this paper: Contrary to the prevalent belief [16], in the presence of well-stabilized SC, an incipient band can significantly enhance T_c . In addition, the induced SC gap on the incipient band can be large. We illustrate this by considering two cases which are motivated by some FeSC materials and will be discussed in detail in Sec. V. These two cases differ essentially in the mechanism driving the SC in the system that exists in the absence of the incipient band. We start with case (ii)a which is the generic case for FeSCs undergoing a Lifshitz transition.

A. Case (ii)a

Our model here consists of one regular hole band at the Γ point with Fermi level DOS N_{h_1} ; one regular electron band forming two pockets at the M points with Fermi level DOS N_e ; and an incipient hole band (h_2) as modeled in case (i). The interband pairing interaction with a cutoff of Λ drives SC in these bands. The origin of the pairing interaction is the assumed presence of strong spin fluctuations at \mathbf{Q} , resulting from particle-hole scattering between these bands as well as the incipient band. It is then reasonable to assume that the same interaction that stabilizes SC in the regular bands couples the incipient band to the rest of the system (namely, the electron pockets). This consideration leads to the same magnitude of the interband interaction between the electron band and the two hole bands (regular and incipient). It will be useful to maintain generality and distinguish the two interband interactions V_{sf_1} and V_{sf_2} connecting the electron band to the bands h_1 and h_2 , respectively. Then, the gap equations are

$$\Delta_e = -V_{sf_1} \Delta_{h_1} L_{h_1} - V_{sf_2} \Delta_{h_2} L_{h_2}, \quad (10)$$

$$\Delta_{h_1} = -2V_{sf_1} \Delta_e L_e, \quad (11)$$

$$\Delta_{h_2} = -2V_{sf_2} \Delta_e L_e, \quad (12)$$

where

$$\begin{aligned} L_{h_1} &= \int_{-\Lambda}^{\Lambda} d\varepsilon N_{h_1} \frac{\tanh \frac{E_{h_1}}{2T}}{2E_{h_1}}, \\ L_e &= \int_{-\Lambda}^{\Lambda} d\varepsilon N_e \frac{\tanh \frac{E_e}{2T}}{2E_e}, \\ L_{h_2} &= \int_{-\Lambda}^{E_g} d\varepsilon \frac{m}{2\pi} \frac{\tanh \frac{E_{h_2}}{2T}}{2E_{h_2}}, \end{aligned} \quad (13)$$

m is the mass of the incipient band. These equations can be rewritten as

$$\begin{aligned} \frac{\Delta_{h_2}}{\Delta_{h_1}} &= \frac{V_{sf_2}}{V_{sf_1}}, \quad \frac{\Delta_{h_1}}{\Delta_e} = -2V_{sf_1} L_e, \\ 1 &= 2L_e [V_{sf_1}^2 L_{h_1} + V_{sf_2}^2 L_{h_2}]. \end{aligned} \quad (14)$$

The same relations hold at T_c with $L_{h_1}/N_{h_1} = L_e/N_e = \ln \frac{2e^{\gamma}\Lambda}{\pi T_c}$ and $L_{h_2} = \frac{m}{2\pi} \int_{-\Lambda}^{E_g} \frac{d\varepsilon}{2\varepsilon} \tanh \frac{\varepsilon}{2T_c}$. These equations in (14) carry all the ‘‘universal’’ information central to our results:

(a) The first equation suggests that the gap induced on the incipient band is related to the ratio of the interband interactions. Recalling that this is the same interaction that couples h_1 and e bands, we expect $V_{sf_1}/V_{sf_2} \approx 1$, despite the fact that h_2 is incipient. Differences in the orbital character of the bands can easily tilt this ratio in either direction, but accounting for this is beyond the scope of this calculation. Thus, we see that the induced gap is generically comparable to, and can in fact be larger than, the preexisting gap. Note also that this last point implies that, within the model, the hole band SC gap will be large until it disappears discontinuously when E_g passes through $-\Lambda$. Of course, a realistic (as compared to BCS) interaction will smear out this behavior.

(b) The third equation tells us about the effect of the incipient band on the preexisting gap. In the absence of the incipient band (simulated by setting $V_{sf_2} = 0$) we have $1 = 2V_{sf_1}^2 L_{h_1} L_e$. Adding the positive-definite V_{sf_2} term forces the combination $L_e L_{h_1}$ to drop. The second equation then suggests that *both* the $T = 0$ electron and hole gaps are increased due to the presence of the incipient band.

(c) The same arguments can be used to justify that T_c is increased in the presence of the incipient band.

(d) This model does not have an interaction threshold for pairing. T_c always exists.

(e) The final piece of information contained in these equations is that the effect of SC on the incipient band in this case is essentially the same as the effect on the regular hole band. The effect of the incipient band itself on the regular bands depends on the mass of the incipient band, such that lighter bands barely affect the gaps and T_c . It is worth noting that neither T_c nor the gap on the incipient band itself is likely to exhibit any discontinuous behavior at the Lifshitz transition.

These equations can be solved for T_c and for the Δ 's at $T = 0$ and the solutions are shown in Fig. 3. As before, we can obtain analytical results for special cases. In the shallow

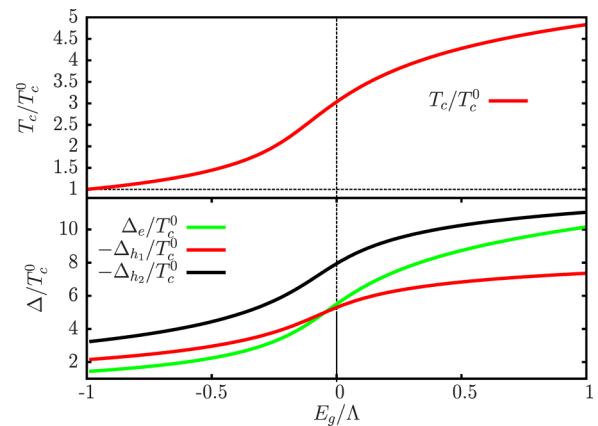


FIG. 3. (Color online) Case (ii)a: Two-dimensional (2D) electron band with regular and incipient hole bands. T_c and gaps as function of E_g . The normalization is with respect to T_c^0 , the critical temperature when $E_g < -\Lambda_{sf}$. Dimensionless interband interactions are $v_{sf_1} = 0.2$ and $v_{sf_2} = 0.3$. Note that Δ_{h_2} is the largest gap in the system.

band region ($0 < E_g \lesssim \Lambda$), if in addition $E_g \gg T_c$,

$$T_c = T_c^0 \exp \left[\frac{1}{\sqrt{2}v_{sf_1}} - \kappa - \sqrt{\kappa^2 + \frac{1}{2(v_{sf_1}^2 + v_{sf_2}^2)}} \right], \quad (15)$$

where now we have defined T_c^0 to be the transition temperature when $E_g < -\Lambda$; it is given by $T_c^0 = \frac{2e^\gamma \Lambda}{\pi} e^{-1/\sqrt{2}v_{sf_1}}$, with $v_{sf_1} = V_{sf_1} \sqrt{N_{h_1} N_e}$, $v_{sf_2} = V_{sf_2} \sqrt{m N_e / 2\pi}$, and

$$\kappa = \frac{\ln \frac{\Lambda}{|E_g|}}{4(1 + v_{sf_1}^2 / v_{sf_2}^2)}. \quad (16)$$

At the Lifshitz transition,

$$T_c^{\text{Lif}} = T_c^0 \exp \left[\frac{1}{\sqrt{2}v_{sf_1}} \left(1 - \frac{1}{\sqrt{1 + v_{sf_2}^2 / (2v_{sf_1}^2)}} \right) \right]. \quad (17)$$

Near $T_c \ll |E_g| \lesssim \Lambda$,

$$T_c = T_c^0 \exp \left[\frac{1}{\sqrt{2}v_{sf_1}} + \kappa' - \sqrt{\kappa'^2 + \frac{1}{2v_{sf_1}^2}} \right], \quad (18)$$

where

$$\kappa' = \frac{\ln \frac{\Lambda}{|E_g|}}{4v_{sf_1}^2 / v_{sf_2}^2}, \quad (19)$$

and when the hole band h_2 becomes a vegetable ($E_g < -\Lambda$), we recover T_c^0 .

B. Case (ii)b

The toy model we choose here is the one where we have a regular electron band crossing the Fermi surface at the M points with Fermi level DOS N_e . The SC is stabilized here via an attractive electron-phonon mediated interaction. We then introduce an incipient hole band at the Γ point (Fig. 1). The pairing interaction between the electron band and this band can be thought of as being due to spin fluctuations and/or phonons. For the moment, we nominally refer to the interactions between bands as originating from spin fluctuations. The microscopic origin of spin fluctuations in the presence of just the incipient band is not obvious, but it is important to note that good Fermi-surface nesting or even states at the Fermi surface are *not* required for a large static particle-hole susceptibility as appears in spin fluctuation pairing [29]. We investigate the effect of these fluctuations on SC, coupling the electron and hole bands via V_{sf} .

We further assume that the cutoff scale for spin fluctuations is larger than that for phonons, i.e., $\Lambda_{sf} > \Lambda_{ph}$. As discussed earlier, the cutoff in spin fluctuation pairing theory is not rigorously defined given that we have approximated the dynamical spin fluctuation interaction by a static interband repulsion, we assume that Λ_{sf} is of order a typical spin fluctuation energy, as determined by the imaginary part of the dynamical susceptibility. As an example, Graser *et al.* [30] estimated the spin fluctuation cutoff to be roughly 100 meV using such a procedure. Following steps similar to those above, we first find the T_c^0 without the incipient band, given by $T_c^0 = \frac{2e^\gamma \Lambda_{ph}}{\pi} e^{1/v_{ph}}$, where $v_{ph} = N_e V_{ph} < 0$.

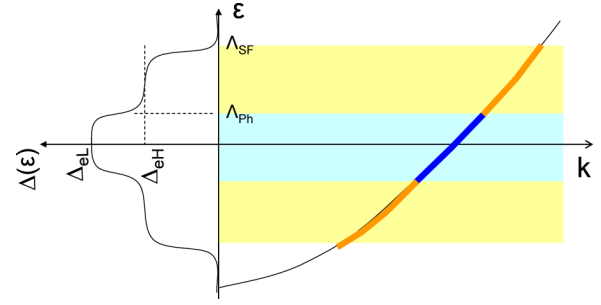


FIG. 4. (Color online) The gap structure on the electron band. The spin fluctuation interactions with the incipient hole band (not shown) have larger cutoff Λ_{sf} . The attractive phonon interactions within Λ_{ph} causes the gap to be larger in the blue region.

Some care is needed in formulating this problem due to the presence of different cutoff scales for the pairing interactions. The main point of departure from conventional BCS modeling is that the gap on the electron pocket is expected to vary at energy scales of Λ_{ph} . In the spirit of the Anderson-Morel model [31,32], we account for this effect by letting the otherwise constant electron gap acquire different values Δ_{eL} for $|\varepsilon| < \Lambda_{ph}$ and Δ_{eH} for $\Lambda_{ph} < |\varepsilon| < \Lambda_{sf}$ (L, H stand for low- and high-energy, respectively, see Fig. 4). Note that allowing Δ to vary with energy is outside the BCS approximation and high-energy renormalizations may be relevant for a quantitative estimate, which is outside the scope of this work.

V_{ph} is only felt by the electron band up to Λ_{ph} . Incorporating these into the gap equations, we arrive at the following:

$$\Delta_{eL} = -V_{ph} \Delta_{eL} L_{eL} - V_{sf} \Delta_h L_h, \quad \Delta_{eH} = -V_{sf} \Delta_h L_h, \quad (20)$$

$$\Delta_h = -2V_{sf} (\Delta_{eL} L_{eL} + \Delta_{eH} L_{eH}),$$

where

$$\begin{aligned} L_{eL} &= 2 \int_0^{\Lambda_{ph}} d\varepsilon N_e \frac{\tanh \frac{E_{eL}}{2T}}{2E_{eL}}, \\ L_{eH} &= 2 \int_{\Lambda_{ph}}^{\Lambda_{sf}} d\varepsilon N_e \frac{\tanh \frac{E_{eH}}{2T}}{2E_{eH}}, \\ L_h &= \int_{-\Lambda_{sf}}^{E_g} d\varepsilon \frac{m}{2\pi} \frac{\tanh \frac{E_h}{2T}}{2E_h}. \end{aligned} \quad (21)$$

We may rewrite these equations as

$$\Delta_{eH} = -V_{sf} \Delta_h L_h, \quad (1 + V_{ph} L_{eL}) \Delta_{eL} = -V_{sf} \Delta_h L_h, \quad (22)$$

$$(1 + V_{ph} L_{eL}) \left(\frac{1}{2V_{sf}^2} - L_h L_{eH} \right) = L_{eL} L_h.$$

We immediately see that, quite generally, from the first equation $\Delta_{eH} \Delta_h < 0$; from the third equation, if V_{sf} is introduced perturbatively, then $1 + V_{ph} L_{eL} > 0$ requiring $\Delta_{eL} \Delta_h < 0$. Note that the introduction of V_{sf} requires $1 + V_{ph} L_{eL} = 0 \rightarrow 1 + V_{ph} L_{eL} > 0$. Then, $V_{ph} < 0$ suggests that T_c and the $T = 0$ gap must increase. Thus, we see that the introduction of the repulsive spin fluctuation coupling to the hole band, normally assumed to be a competing mechanism [33], actually aids the electron-phonon SC in this case. This is the core of the bootstrapping effect described in the Introduction.

In order to understand the effect of the relative size of the cutoffs for the two mechanisms, let us focus, for simplicity, on the regular band case where $E_g > \Lambda_{sf}$. We define $v_{sf} \equiv \sqrt{N_h N_e} V_{sf} > 0$ and $v_{ph} \equiv N_e V_{ph} < 0$. The solution to T_c for any $\Lambda_{sf}/\Lambda_{ph}$ is given by

$$\ln \frac{2e^\gamma \Lambda_{sf}}{\pi T_c} = \frac{1}{\sqrt{2}v_{sf}} \left[\frac{-[r + l(2 - rl)] + \sqrt{[r + l(2 - rl)]^2 + 4(1 - l^2)(1 - rl)}}{2(1 - rl)} \right] + \frac{l}{\sqrt{2}v_{sf}}, \quad (23)$$

where $l \equiv \sqrt{2}v_{sf} \ln \frac{\Lambda_{sf}}{\Lambda_{ph}}$, $r = -\frac{v_{ph}}{\sqrt{2}v_{sf}}$. We now show that this correctly reduces to the well-known cases when $\Lambda_{sf} \rightarrow \Lambda_{ph} = \Lambda$ and when $\Lambda_{ph} \rightarrow 0$. It is clear from Eqs. (20) and (21) that in the limit $\Lambda_{sf} \rightarrow \Lambda_{ph} = \Lambda$, so that $L_{eH} \rightarrow 0$, there is no ‘‘phase space’’ for Δ_{eH} . This then reduces to the usual model with two bands whose T_c is given by

$$\ln \frac{2e^\gamma \Lambda_{ph}}{T_c^{2\text{band}}} = \frac{1}{\sqrt{2}v_{sf}} \left[\frac{-r + \sqrt{r^2 + 4}}{2} \right]. \quad (24)$$

The same is achieved by setting $l = 0$ in Eq. (23). In the other limit, $\Lambda_{ph} \rightarrow 0$, we note that $L_{eL} \rightarrow 0$ and $L_{eH} \rightarrow \ln \frac{2e^\gamma \Lambda}{\pi T_c}$ (or equivalently $l \rightarrow \sqrt{2}v_{sf} \ln \frac{2e^\gamma \Lambda}{\pi T_c}$). This means that Eq. (23) needs to be solved for $\ln \frac{2e^\gamma \Lambda}{\pi T_c}$. In doing so, using $1 - rl \neq 0$ we end up with $l = 1$ or $\ln \frac{2e^\gamma \Lambda}{\pi T_c} = 1/\sqrt{2}v_{sf}$. This is the well known T_c for the two-band toy $s \pm$ SC model.

Having convinced ourselves that the model reproduces the two limits of applicability, we now look at the general solution, plotted in Fig. 5. As expected, T_c generally increases when v_{sf} is increased. There is, however, a possibly interesting interplay with the ratio $\Lambda_{sf}/\Lambda_{ph}$: as we increase Λ_{ph} , the T_c increases (all the way up to where the two cutoffs are comparable). It suggests that the presence of both mechanisms should help increase T_c .

Returning to the incipient problem, we wish to study T_c and the gaps on the two bands as a function of E_g . We perform the usual change with $N_h \rightarrow m/2\pi$ and work in the limit $\Lambda_{sf} \rightarrow \Lambda_{ph}$. These results are plotted in Fig. 6. We see that not only is the T_c enhanced due to the presence of the incipient

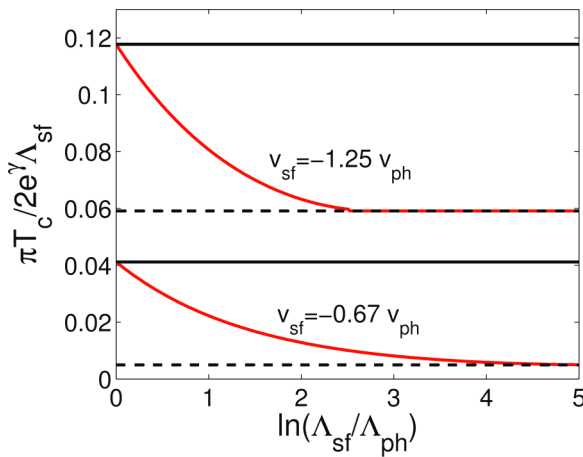


FIG. 5. (Color online) Red solid lines: T_c vs $\ln \Lambda_{sf}/\Lambda_{ph}$ for two different values of v_{sf} , showing that T_c increases as Λ_{ph} is increased all the way up to $\Lambda_{ph} = \Lambda_{sf}$. For each v_{sf} , dashed black lines correspond to T_c for $\Lambda_{ph} = 0$, while solid black lines correspond to T_c for $\Lambda_{ph} = \Lambda_{sf}$. Here, $v_{ph} = -0.2$.

band as expected from the above discussion, but the crossover through the Lifshitz transition is considerably less abrupt than in case (i). We refer to this key result in our discussion of FeSe monolayers on STO (see Sec. V).

C. Effect of three dimensionality of the incipient band

We have so far only addressed 2D systems where the conversion of the phase-space \vec{k} integral to energy integral, near the Lifshitz point, was done via $\int \frac{d^2k}{(2\pi)^2} = \frac{m}{2\pi} \int d\varepsilon$ for all energies (the constant density of states for parabolic bands). This property changes in 3D since for a hole band with dispersion $-k^2/2m + E_g$,

$$N_h(\varepsilon) = N_h^{3D} \text{Re} \sqrt{2 \frac{E_g - \varepsilon}{\Lambda}}, \quad (25)$$

where N_h^{3D} is given by $a\sqrt{\frac{\Lambda}{2}}$, where $a \equiv \frac{(2m)^{3/2}}{4\pi^2}$. We give details in this less transparent case in the Appendix. Below, we give a qualitative discussion with the focus on the question whether the previous results for a 2D hole band are substantially modified.

The weighting factor $\text{Re} \sqrt{E_g - \varepsilon}$ near the top of the band in the energy space proves harmful for the T_c in the one-band incipient case (i)a, as can be seen from Fig. 7(a) where we compare the 2D (red curve) with the 3D version (green dashed curve). It is clear that T_c in 3D is suppressed significantly due to the depletion of the DOS relative to the 2D case within weak coupling as the band becomes incipient. In fact, there is no SC in the 3D incipient band case for case (i)a. SC is present for a shallow band for any strength of attractive

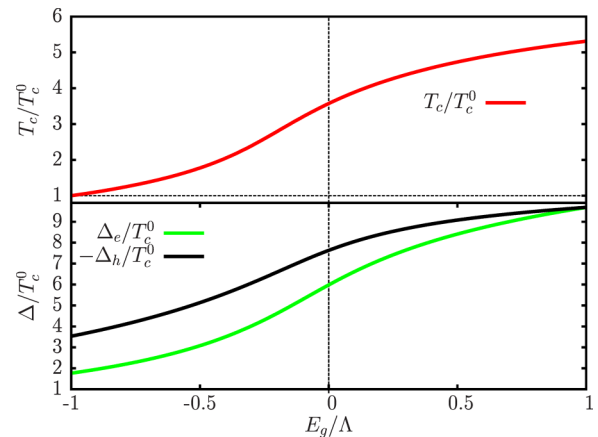


FIG. 6. (Color online) Case (ii)b: 2D electron and hole bands. T_c normalized to T_c^0 , the transition temperature when $E_g < -\Lambda_{sf}$, and gaps as a function of E_g , normalized to $\Lambda_{sf} = \Lambda_{ph}$. Dimensionless interactions are $v_{ph} = -0.3$ and $v_{sf} = 0.3$.

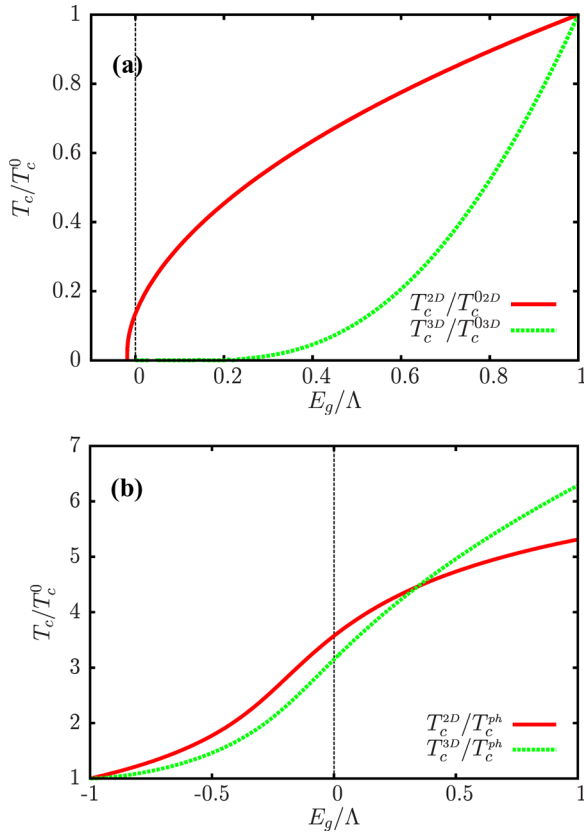


FIG. 7. (Color online) Comparison of 2D (red curve) and 3D (green curve) scenarios. (a) Case (i)a T_c/T_c^0 vs E_g/Λ , where T_c^0 is the value of T_c at $E_g = \Lambda$. The dimensionless phonon interaction was taken as $v_{ph} = -0.5$ for 2D and $v_{ph} = -0.2\sqrt{2}$ for 3D, with DOS ratio $m/(2\pi N_h^{3D}) = 1$. (b) Same, but for case (ii)b, with $v_{ph} = -0.3$ and $v_{sf} = 0.3$ for both 2D and 3D. For this plot, the special case $\Lambda_{ph} = \Lambda_{sf} = \Lambda$ was adopted.

interaction in the form of the BCS essential singularity $T_c \sim \exp(-1/a\sqrt{E_g}V_{ph})$, but completely suppressed for an incipient band. This result originates in the 3D analog of the integral of Eq. (3). The additional square root that removes the singular nature of the integrated kernel as $T_c \rightarrow 0$ as compared to the case in 2D, where the kernel is $\tanh(\varepsilon/2T_c)/\varepsilon$. Thereby, the influence of T_c on the value of the integral is reduced in 3D and no weak-coupling solution is possible at or beyond the Lifshitz transition. Only if we allow for strong-coupling SC in the sense that T_c is larger than the cutoff Λ do we find SC for a 3D incipient band.

Thus, the question arises if a similar conclusion holds in the multiband scenarios discussed in this work, i.e., whether or not SC is strongly suppressed by such 3D effects. Even without an explicit calculation, we see that the log singularity of the BCS integral is again lifted. The value of the integral can be large while the influence of T_c on this value is small. In order to compare 2D and 3D, we choose a reference point such that the 3D DOS equals the 2D DOS at $E_g = \Lambda/2$. We now calculate the T_c enhancement of a phonon mediated SC with a 3D incipient hole band and compare the result with case (ii)b in Fig. 7(b). We observe a rather moderate reduction of the enhancement in the incipient region with a 3D hole band

(dashed green curve) as compared to the 2D case (red curve). In the Appendix, we show further results where we repeat the calculations of the main text with a 3D hole band. Similar to Fig. 7, we observe that a 3D hole band can bootstrap SC at the Fermi level almost as effectively as a 2D band.

V. DISCUSSION

The main result of our analysis is that, for the Fe-based superconductors, the appearance of superconductivity on an incipient band is a natural consequence of multiband pairing, rather than an indication of strong-coupling physics. Here, we discuss how our results relate to various controversies in the field for particular materials at the present time, in a rather simplified way that neglects various complications, such as the exact number of bands, orbital character, etc. In each of these cases, more detailed theoretical work is needed to address the issue of the consequences for pairing of incipient bands in the system since the vast majority of the detailed calculations have assumed pairing only at the Fermi surface.

LiFeAs. The fascinating experiment which revitalized this discussion (Miao *et al.* [16]) showed the persistence of large gap on a hole band as it underwent a Lifshitz transition upon Co doping. The lack of any significant signature of this Lifshitz transition in either T_c or the ARPES gap magnitude suggested to the authors of this work that weak-coupling physics, which relies on Fermi surface interactions, could not be at play. They furthermore argued that induced superconductivity, due to the interactions between the bands at the Fermi surface and “proximity coupled” in momentum space to the incipient band, could not be occurring because the gap observed there was the largest in the system. Subsequently, Hu *et al.* [20] considered a multiband situation superficially similar to our case (ii)b, and found that gaps the size observed in the experiment required strong coupling, i.e., dimensionless interband interactions of order 1, and in addition reported that their equations required a critical interaction strength to generate a finite T_c . They claimed that their results qualitatively supported the conclusions of Ref. [16].

On the other hand, we have demonstrated that effects of the type observed by Miao *et al.* [16] are rather easy to generate in a case (ii)a situation. This is certainly characteristic of LiFeAs, which has electron and at least one and possibly two hole pockets at the Fermi level [34–36] even with substantial Co doping. In Fig. 8, we compare the gap on the incipient band as a function of E_g for cases (i)b and (ii)a. While we have already seen in Fig. 3 that, depending on the ratio of the interactions and the DOS, the gap on the incipient band can be the largest in the system, we now clearly see that it is only weakly suppressed as the band sinks below the Fermi level. We furthermore disagree with the conclusions of Hu *et al.* [20] because it appears to be based on an incorrect formulation of the multiband pairing problem. In Eq. (6) of their paper, they include the interband interaction V_2 into the intraband kernel. In doing so, the problem they solve actually maps to our intraband pairing scenario [case (i)a] and hence they see the threshold for the pairing interaction. One can easily check that, as a result of this, their gap equation does not reduce to the classic two-band $s\pm$ superconductivity as discussed, e.g.,

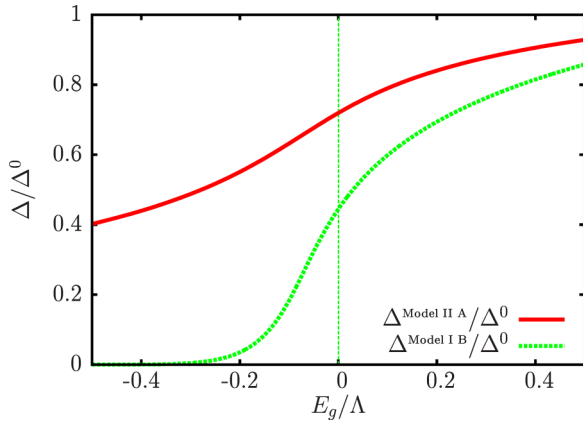


FIG. 8. (Color online) Comparison of the incipient hole gap in case (i) (green) and case (ii) (red) taken from Figs. 2(b) and 3, respectively. Gaps are normalized to their value $\Delta_0 < 0$ at $E_g = \Lambda$.

in Ref. [6] when the intraband interaction $V_1 = 0$, whether or not one of the bands is incipient.

The rough conclusions that we present here may be of considerable relevance for theoretical calculations of the pairing state of LiFeAs. Because it is nonmagnetic, with no obvious nesting, and because high-quality ARPES data (including precise measurements of anisotropic gaps on various Fermi-surface sheets) have been available due to the nonpolar surfaces of this material, LiFeAs has been perceived as something of a challenge by theorists. Several proposals have been made, both based on DFT-derived Fermi surfaces [37], or on the rather different ARPES-determined Fermi surfaces [38–41]. At issue has been the size of the gaps on the rather small inner hole xz/yz Fermi surface pockets reported by ARPES which are those which undergo Lifshitz transitions upon electron doping. Empirically, these gaps are the largest in the system, and this property is retained upon electron doping, even when the bands responsible fall below the Fermi level. The calculations in question all considered pairing only at the Fermi level, and generally agreed on the gap functions obtained for the electron and outer hole pockets, but disagreed on the sizes of the gaps on the inner hole bands. In some cases, good agreement with the gaps on the smaller hole pockets was found, based on claims of improved calculational schemes [40,41]. In the case of the only fully 3D spin fluctuation pairing calculation (Ref. [38]), the gaps on these small pockets were found to be too small compared to experiment, and the authors speculated that this might be due to the neglect of states away from the Fermi level, including states in incipient bands. Our calculations here suggest that such effects could indeed be important, and it may be that for such systems Eliashberg or other calculational schemes which account for the dynamics of the pairing interaction are required.

FeSe monolayers on STO. While the lattice parameters of the FeSe monolayers grown on STO, with T_c 's of 70 K or higher, are a few percent larger than that of the bulk, it has proven difficult to reproduce the experimental Fermi surface by DFT calculations for a 2D FeSe layer, accounting only for the strain. Most researchers believe that the O vacancies in the STO play an important role by electron doping the FeSe monolayer and thereby pushing down the Γ -centered hole band

[42]. Another clue to the physics of these systems, and the influence of the substrate, was recently provided by ARPES measurements [43], which indicated via the observation of “replica bands” the presence of a strong electron-phonon interaction, probably originating from the substrate [43]. It has recently been argued that the electron-phonon interaction must be quite peaked near momentum transfer $\mathbf{q} = 0$ to explain this observation [44], supporting the basic scenario for high- T_c proposed in Refs. [43,45]. Reference [44] in fact argued that high T_c in this unusual system could be obtained from the STO forward scattering phonons alone, but did not offer a microscopic justification. In fact, the recent observation of high- T_c superconductivity in FeSe flakes doped by liquid gating techniques [46] suggests that spin fluctuations may be as relevant as phonons for pairing in these systems.

Considering only the bands at the Fermi surface, the high T_c in this system and the form of the order parameter are puzzling. We do not expect electron-phonon interactions in the FeSe to be strong enough to explain a T_c of 70 K or above [47], such that a simple s wave from attractive interactions alone seems unlikely, even if boosted by STO phonons. The forward scattering nature of the essential phonon processes then means that phonons cannot contribute to the interband interaction. On the other hand, the spin fluctuation interaction by itself should lead naively to nodeless d wave [since $\chi(\mathbf{q}, \omega)$ will be peaked at the wave vector connecting the electron pockets], as in the arguments given for alkali intercalates [13,14]. There are some indications that the system does not have a sign-changing order parameter, however. For example, STM measurements by Fan *et al.* [48] show a full gap which is suppressed only by magnetic impurities, similar to a “plain” s -wave superconductor. Note that these arguments, if correct, would also rule out states of the “bonding-antibonding s -wave” type [3], which we do not discuss here.

The arguments in this paper favor the “dark horse” candidate for pairing, the incipient s_{\pm} state, with a large gap magnitude on both the electron pockets at the Fermi surface band and the incipient hole band well below it. The spin fluctuations have been shown capable of substantially enhancing a weak phonon T_c . In order to account for the experimental situation, we slightly modify the model case (ii)b. It was shown that the hole band is pushed below the bottom of the electron band [43], but the presence of the replica band suggests that even the hole band is in the range of the phonon cutoff. Thus, we consider a shallow electron band (band minimum E_e) together with an incipient hole band, but otherwise similar, situation as in case (ii)b. We include phonon coupling in the part of the incipient hole band within the phonon cutoff. The model is shown in the inset of Fig. 9. To illustrate the possibility of incipient spin fluctuation bootstrap more concretely, we plot in Fig. 9 the possible T_c enhancements over a phonon bare critical temperature T_c^{ph} that one would obtain in a naive calculation, i.e., the T_c in the absence of interband spin fluctuations and disregarding all band-edge effects ($E_e = -\Lambda_{\text{ph}}$). The cutoff in spin fluctuation pairing theory is ill defined, but may be roughly identified with the energy scale of the spin fluctuation Eliashberg function in Ref. [49] for bulk FeSe. This Eliashberg function has appreciable weight for energies as high as 800 meV and a peak at 600 meV. We account for this with a rough estimate

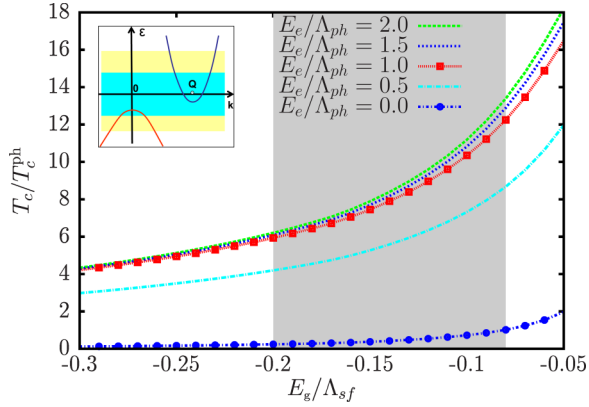


FIG. 9. (Color online) T_c as a function of the band edge E_g of the incipient hole band for several band extrema for the electron band E_e . Big red dots highlight the curve $T_c(E_g)$ where $E_e = -\Lambda_{ph}$ and big blue dots $E_e = 0$ where the electron band reaches the Fermi level. The experimental situation of a shallow band ($-\Lambda_{ph} < E_e < 0$) is in-between these curves. The shaded gray region is a range of E_g/Λ_{sf} for $E_g = 80$ meV and the sf cutoff ($\Lambda_{sf} = 400$ to 1000 meV) that is a rough estimate based on calculations for bulk FeSe [49]. We use $v_{ph} = -0.2$, $v_{sf} = 0.25$, $\Lambda_{sf} = 600$ meV, and $\Lambda_{ph} = 100$ meV. For these parameters, $T_c^{ph} = 9$ K.

represented by the gray shaded area in Fig. 9 that highlights the range of E_g/Λ_{sf} for $E_g = 80$ meV and $\Lambda_{sf} = 400$ to 1000 meV.

For the choice of parameters used in the figure, T_c^{ph} is 9 K, and that the gray region suggests that enhancements of order 6–12 with respect to T_c^{ph} are possible. Note, however, that this range is quite sensitive to the choices of interactions and the ratio of the cutoffs, which are poorly known, so the reader should not take the numbers particularly seriously. Our message is simply that a weak bare phonon interaction can be used to create a large T_c , even with a spin fluctuation interaction which may be weakened by the incipient band.

Of course, the s_{\pm} state found here naively has the same difficulty with the results of Ref. [48]. However, since impurities scatter elastically, one expects substantial suppression of pair-breaking effects due to the gap sign change in incipient band pair systems. This question is currently under active investigation.

FeSe intercalates. Here, we intentionally lump together, without particularly good justification, (a) alkali-doped FeSe intercalates such as KFe_2Se_2 , (b) ammoniated FeSe intercalated such as $\text{Li}_{0.56}(\text{NH}_2)_{0.53}(\text{NH}_3)_{1.19}\text{Fe}_2\text{Se}_2$ [50]; and (c) recently discovered lithium iron selenide hydroxides $\text{Li}_{1-x}\text{Fe}_x(\text{OH})\text{Fe}_{1-y}\text{Se}$. (a) and (c) have been shown to have Fermi surfaces without Γ -centered hole pockets, similar to the FeSe/STO monolayers [51]. There are no ARPES Fermi-surface measurements of the materials in category (b) to our knowledge, due to sample volatility, but it seems reasonable to assume since FeSe interlayer distances are comparable, and T_c 's similar [of order 40 K for (a)–(c)], that they may be in this class.

Since T_c is not as high as in the FeSe/STO monolayers, it is tempting to speculate that these systems must all belong to class (i)b. That is, in these systems we have no evidence

(to our knowledge) that the electron-phonon interaction plays any exceptional role; we assume, therefore, that it may be neglected, leaving a strongly suppressed incipient s_{\pm} superconducting channel to compete with what should be a much more robust d -wave interaction present in all systems [52]. Ultimately, all case (i)b systems should be d wave as well. In some systems, evidence against d wave has been presented already, however. For example, in KFe_2Se_2 , ARPES measurements failed to find any anisotropy of the gap on the tiny Z -centered hole Fermi surface pockets in that system [53]. But, if we account for *these* states, the appropriate model is then not (i)b but (ii)a, with a 3D incipient band, which we have shown leads to a substantially enhanced T_c and large gap on the incipient band. Thus, from our perspective, these systems could still be d wave or incipient s_{\pm} , depending on details.

In this work, we have used very simple models to investigate the fundamental nature of SC in connection with an incipient band. We believe these models account for most qualitative effects in the systems discussed above. Improvement to these models can be made by including dynamical effects in the interaction, and by including the intraband Coulomb interaction. We note that the renormalized Coulomb pseudopotential may be effectively reduced by an incipient band and thus give rise to a bootstrap mechanism even if T_c^{ph} in the absence of the incipient band were zero. Finally, we have checked that one can arrive at similar conclusions to those contained in this work in an Eliashberg approach where the bands are parabolic and the interaction is constant up to the Matsubara summation cutoff, similar to the BCS “box” interaction [54].

Note finally that we have assumed in the numerical evaluations of the theory above that spin fluctuations with the incipient band can be significant, and in particular for case (ii)a that they can be of the same order as the Fermi surface spin fluctuation interband interaction. While this appears to us to be quite reasonable, given that magnetic interactions are defined over large energy scales of order $\Lambda_{sf} \gg E_g$, these assumptions should be justified by concrete calculations, which are currently in progress.

VI. CONCLUSION

We have investigated pairing on bands away from the Fermi surface within a weak-coupling multiband BCS approximation. This is possible because the pairing interaction has a finite spread around the Fermi surface. Taking advantage of this spread we identify four instances for a hole band: (1) regular hole band: when the extremum of the band is far from the cutoffs; (2) shallow band: when the extremum of a band is above the Fermi level but within the cutoff; (3) incipient band: when the extremum of a band is below the Fermi surface but still within the cutoff; and (4) vegetable band: does not take part in pairing. This paper focuses on the shallow and incipient band pairings. We have further identified two cases of pairing which have qualitatively different results in the shallow and incipient regions: Case (i) where pairing is driven by interactions with the incipient band and case (ii) where pairing is induced on the incipient band. We have argued that most work in the literature has only addressed case (i) and prematurely concluded that weak-coupling theories cannot be applied to certain family of FeSCs where evidence for robust pairing was found in the

incipient bands. We argue in our work that case (ii) has all the experimentally observed features within weak coupling.

Our case-by-case results are the following. Case (i): We have considered simple models for phonon driven and spin fluctuation driven SC and confirmed the previously known results that pairing in the incipient scenario is strongly suppressed. A minimum attractive strength for the SC instability is only needed in case (i)a. Case (ii): We consider phonon driven and spin fluctuation driven SC (from regular bands) and show that the strength of induced pairing in the shallow and incipient bands can be large, and comparable to the preexisting bands. The T_c is enhanced quite generally in the presence of an incipient band connected to the Fermi surface by finite- \mathbf{q} spin fluctuation scattering. In this context, we discussed the bootstrapping effect of spin fluctuations on the electron-phonon SC. All these effects in case (ii) are more pronounced in 2D, but not qualitatively so. We have shown that the dimensionality of the incipient band only plays a significant role for the case (i)a model. We have presented a simple model to study the effect of different cutoffs for the phonon driven and spin fluctuation driven SC and indicated that the phonon mechanism aids the spin fluctuation mechanism. Finally, we discussed the results in the concrete context of LiFeAs, FeSe intercalates, and FeSe monolayers on STO, which have been reported to have similar Fermi surfaces missing Γ -centered hole pockets, and concluded that induced superconductivity in incipient bands may play a role in all these systems, for somewhat different reasons.

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APPENDIX: 3D INCIPIENT HOLE BAND

In this appendix, we derive the effect on T_c and the gaps on the various bands if the DOS is not constant as in 2D but shows the well-known square root behavior of a 3D electron gas. We give details for the single incipient band solution because the results can be used later in the multiband models. The equation that determines T_c reads as in this case

$$\frac{1}{v_{3D}} = - \int_{-\Lambda}^{E_g} d\varepsilon \operatorname{Re} \sqrt{\frac{E_g - \varepsilon}{|E_g|}} \frac{1}{2\varepsilon} \tanh\left(\frac{\varepsilon}{2T_c}\right), \quad (\text{A1})$$

where $v_{3D} = -\sqrt{|E_g|}a|V_{ph}|$ and $a = (2m)^{\frac{3}{4}}/(2\pi^2)$. Thus, we are lacking a natural reference since any density-of-states variation is usually disregarded in conventional methods of SC, with the notable exception of the density functional theory of superconductors. In the present situation for the single

incipient band we arbitrarily measure our T_c in units of the value at $E_g = \Lambda$. The coupling at our reference $E_g = \Lambda$ is then simply $v_{3D}^0 = -a|V_{ph}|\sqrt{\Lambda}$. Before we resort to numerics, again, we want to discuss special cases.

1. Shallow band

In 3D, if the integral (A1) includes $\varepsilon = 0$, we may introduce L_0^{3D} by

$$L_0^{3D} = \int_0^{E_g} d\varepsilon \sqrt{1 - \frac{\varepsilon}{E_g}} \frac{1}{2\varepsilon} \tanh\left(\frac{\varepsilon}{2T_c}\right) + \int_0^\Lambda d\varepsilon \sqrt{1 + \frac{\varepsilon}{E_g}} \frac{1}{2\varepsilon} \tanh\left(\frac{\varepsilon}{2T_c}\right). \quad (\text{A2})$$

In the weak-coupling limit we can split the integral around a cutoff $E_g > C \gg T_c$. Then, Eq. (A1) reads as

$$-\frac{1}{v_{3D}} = \int_0^C d\varepsilon \frac{1}{2\varepsilon} \left(\sqrt{1 - \frac{\varepsilon}{E_g}} + \sqrt{1 + \frac{\varepsilon}{E_g}} \right) \tanh\left(\frac{\varepsilon}{2T_c}\right) + \int_C^{E_g} d\varepsilon \frac{\sqrt{1 - \frac{\varepsilon}{E_g}}}{2\varepsilon} + \int_C^\Lambda d\varepsilon \frac{\sqrt{1 + \frac{\varepsilon}{E_g}}}{2\varepsilon}. \quad (\text{A3})$$

If, in addition, $E_g \gg C \gg T_c$, we obtain in the first term an integrand proportional to $\tanh(\varepsilon/2T_c)/\varepsilon$ and, thus, the original BCS problem except for some high-energy renormalization prefactor P :

$$\ln P = \int_C^{E_g} d\varepsilon \frac{\sqrt{1 - \frac{\varepsilon}{E_g}}}{2\varepsilon} + \int_C^\Lambda d\varepsilon \frac{\sqrt{1 + \frac{\varepsilon}{E_g}}}{2\varepsilon} - \ln \frac{\Lambda}{C}, \quad (\text{A4})$$

and we arrive at the solution

$$T_c^{3D}(E_g \gg T_c) = P \frac{2e^\gamma}{\pi} \Lambda e^{\frac{1}{v_{3D}}}. \quad (\text{A5})$$

Because of the fact that $E_g \gg C$, we see that the lower limit of the integral in P of Eq. (A4) will roughly cancel the $\ln(\Lambda/C)$ and, thus, P is independent on C . Furthermore, we observe in Fig. 10 that for the weak-coupling limit, $P(E_g)$ is constant and we may approximately write

$$T_c^{3D}(E_g \gg T_c) \approx T_c^0 e^{\frac{1}{v_{3D}} - \frac{1}{v_{3D}^0}}. \quad (\text{A6})$$

This analysis is always valid if T_c is small enough. We conclude for $E_g \gg T_c$ that superconductivity in a 3D free-electron band is induced by an arbitrary small attractive interaction via the BCS essential singularity in the weak-coupling limit. Due to the dependence on the DOS, the effective coupling changes with E_g as $\sim \sqrt{E_g}$.

2. Lifshitz transition

In the following, we show that even for $E_g = 0$ already, we can find parameters, such that T_c vanishes and, thus, the simple BCS picture is substantially modified. Setting $E_g = 0$, we find

$$\frac{\sqrt{\Lambda}}{v_{3D}^0} = - \int_0^\Lambda d\varepsilon \frac{\tanh\left(\frac{\varepsilon}{2T_c}\right)}{2\sqrt{\varepsilon}}. \quad (\text{A7})$$

Even for $T_c \rightarrow 0$, the resulting equation is integrable while the 2D analog diverges. Moreover, in the limit $T_c \rightarrow 0$, the above

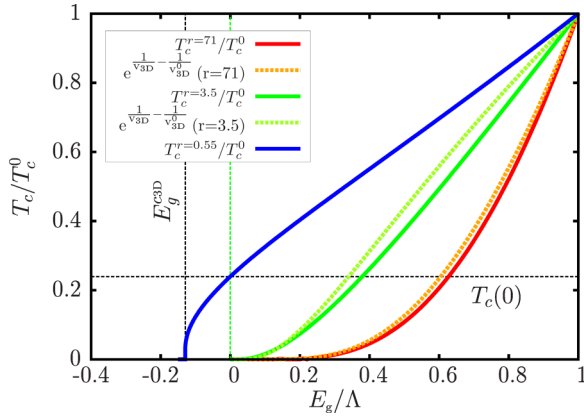


FIG. 10. (Color online) T_c/T_c^0 for a 3D hole band for $r \equiv \frac{\Lambda}{2T_c^0} = 71$ (red), 2.5 (green), and 0.55 (blue). The weak-coupling ratio $r = \frac{\Lambda}{2T_c^0}$ is indicated for each data set in the legend. The parameters for $r = 71, 2.5,$ and 0.55 are $v_{\text{ph}} = -0.2\sqrt{2}, -0.5\sqrt{2},$ and $-2.0\sqrt{2}$, respectively, and the 2D vs 3D DOS ratio is chosen such that $m/(2\pi N_h^{3D}) = 1$. We show Eq. (A6) as a dashed line for $r = 71$ and 3.5 in dashed orange and dashed green lines, respectively.

equation requires $v_{3D}^0 = 1$ to be satisfied. If the coupling gets smaller, no choice of T_c can make the integral large enough to match v_{3D}^0 and only the trivial solution $T_c = 0$ is possible. Note that the integral in Eq. (A7) can be scaled with the result

$$-\frac{\sqrt{\Lambda}}{v_{3D}^0} = \sqrt{\frac{T_c}{2}} \int_0^{\frac{\Lambda}{2T_c}} d\xi \frac{\tanh(\xi)}{\sqrt{\xi}}. \quad (\text{A8})$$

Proceeding by partial integration and assuming the weak-coupling limit, we find

$$-\frac{\sqrt{\Lambda}}{v_{3D}^0} = \sqrt{\Lambda} - \sqrt{T_c} \phi, \quad (\text{A9})$$

where

$$\phi = \sqrt{2} \int_0^\infty d\xi \sqrt{\xi} \operatorname{sech}^2(\xi) = 1.072. \quad (\text{A10})$$

We solve Eq. (A9) with the result

$$T_c(E_g = 0) = \frac{\Lambda}{\phi^2} (1 + v_{3D}^0)^{-2}. \quad (\text{A11})$$

Equation (A9) requires $-v_{3D}^0 > 1$ to have a real solution for T_c and points out that for sufficiently low couplings, SC is completely suppressed already when the band touches the Fermi level.

3. Incipient band

If $-E_g \gg T_c$, on the other hand, the integral in Eq. (A1) is only weakly dependent on T_c since $\tanh(\frac{\varepsilon}{2T_c}) \approx 1$ and, as in 2D, we arrive at the conclusion that superconductivity is completely suppressed. To determine E_g^{c3D} , where $T_c(E_g)$ vanishes, we solve the integral for $\tanh(\varepsilon/2T_c) = 1$:

$$\int_{|E_g|}^{\Lambda} d\varepsilon \frac{\sqrt{\varepsilon - |E_g|}}{2\varepsilon} = \sqrt{\Lambda} \left\{ \sqrt{1 - \frac{|E_g|}{\Lambda}} - \sqrt{\frac{|E_g|}{\Lambda}} \arccos \left[\sqrt{\frac{|E_g|}{\Lambda}} \right] \right\} \quad (\text{A12})$$

and expand for small E_g/Λ that we combine with Eq. (A1) with the result

$$E_g^{c3D} = 2\Lambda \left[-1 - (v_{3D}^0)^{-1} + \frac{\pi^2}{4} - \frac{\pi}{\sqrt{2}} \sqrt{-1 - (v_{3D}^0)^{-1} + \frac{\pi^2}{8}} \right]. \quad (\text{A13})$$

Note that this equation determines the critical E_g only if T_c is not already zero at $E_g = 0$. The reason is that Eq. (A12) assumes that Eq. (A1) can be satisfied for any choice of T_c which, as noted earlier, is not the case in a weakly coupled system. From Eq. (A11) for $T_c(0)$ we expect that setting $v_{3D}^0 = 1$ in the above Eq. (A13) we are at the transition and in fact $E_g^{c3D}(v_{3D}^0 = -1) = 0$. Thus, the formula (A13) only applies for $v_{3D}^0 < -1$. The limit for $v_{3D}^0 \rightarrow -\infty$ of E_g/Λ is $(-4 + \pi^2 - \pi\sqrt{\pi^2 - 8})/2 \approx 0.79$. For the numerical investigation over the entire range of E_g , as mentioned above we arbitrarily fix our reference T_c^0 to the value for $E_g = \Lambda$ and evaluate the integral numerically. The resulting T_c/T_c^0 is shown in Fig. 10.

4. Effect of a 3D incipient hole band in the cases (i)b, (ii)a, and (ii)b

While we have seen that an incipient 3D band requires strong coupling to be SC at the Lifshitz transition, the

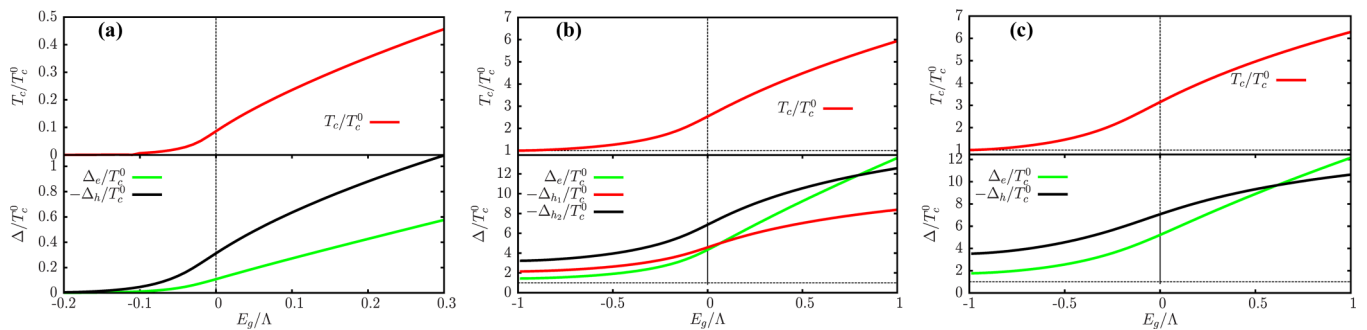


FIG. 11. (Color online) Comparison of 3D with 2D results for the cases (i)b, (ii)a, and (ii)b in panels (a), (b), and (c), respectively. We specify the DOS ratio so that $m/(2\pi N_h^{3D}) = 1$. (a) The coupling parameters are $v_{\text{sf}} = -0.3$ for (a), $v_{\text{sf}1} = v_{\text{sf}2} = 0.3$ for (b), and $v_{\text{ph}} = -v_{\text{sf}} = -0.3$ for (c). The plots (a), (b), and (c) have to be compared to Figs. 2(b), 3, and 6, respectively.

conclusion that such a 3D band does not take part in multiband SC cannot be drawn at this stage. As we have already discussed in the main text, in order to understand why this is the case, consider the general difference between the integral of Eq. (A1) and the 2D case of Eq. (3). The additional square root lifts the BCS singularity in the integral (10). What determines

the enhancement of T_c , however, is the integral in Eq. (A12). If the incipient hole band has a 3D dispersion, we need to replace L_h of Eq. (22) and L_{h_2} of Eq. (10) with $(N_h^{3D} 2\pi/m)L_0^{3D}$ or $(N_h^{3D} 2\pi/m)L_0^{3D}$, respectively. We repeat the calculations for the cases (i)b, (ii)a, and (ii)b for a 3D incipient hole band and present the result in Fig. 11.

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